

(12) United States Patent Koyama

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- (54) ANTIREFLECTION COATING, OPTICAL SYSTEM, AND OPTICAL INSTRUMENT
- (71) Applicant: Olympus Corporation, Tokyo (JP)
- (72) Inventor: Masanori Koyama, Tachikawa (JP)
- (73) Assignee: Olympus Corporation, Tokyo (JP)
- (*) Notice: Subject to any disclaimer, the term of this

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patent is extended or adjusted under 35 U.S.C. 154(b) by 113 days.

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- (30) Foreign Application Priority Data

Jun. 10, 2011 (JP) 2011-130083

(51) Int. Cl.
G02B 27/00 (2006.01)
G02B 1/11 (2015.01)

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Primary Examiner — Pascal M. Bui-Pho
Assistant Examiner — Sharrief Broome
(74) Attorney, Agent, or Firm — Arent Fox LLP; Steven
Weisburd

(57) **ABSTRACT**

An antireflection coating has a band ranging from the visible light range to the near infrared range. The antireflection coating has a deposition structure made up of twelve layers in which layers of a high refractive index material having a refractive index nH of 1.95 to 2.32 and layers of a low refractive index material having a refractive index of 1.35 to 1.46 are deposited alternately, wherein the reflectance of the antireflection coating is not higher than 1.5% in the wavelength range of 400 nm to 680 nm and not higher than 2.0% in the wavelength range of 680 nm to 1350 nm.

	(=010101)
G02B 1/115	(2015.01)

(52) **U.S. Cl.**

CPC G02B 1/11 (2013.01); G02B 1/115 (2013.01)

(58) Field of Classification Search

CPC G02B 5/18; G02B 5/1809; G02B 5/1876; G02B 5/1814; G02B 5/1852; G02B 5/1847; G02B 5/1866; G02B 1/041; G02B 27/4211; G02B 2006/12107; G02B 27/0037; G02B 27/44

5 Claims, 26 Drawing Sheets



US 9,423,529 B2 Page 2

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U.S. Patent Aug. 23, 2016 Sheet 1 of 26 US 9,423,529 B2





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U.S. Patent Aug. 23, 2016 Sheet 2 of 26 US 9,423,529 B2

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NESS	EXAMPLE 3	REFRACTIVE INDEX OF SUBSTRATE		0.21	0.34	0.57	0.33	0.81	0.15	1.51	0.11	0.86	0.41	0.40	1.22	
CAL FILM THICKN		REFRACTIVE INDEX OF SUBSTRATE		0.17	0.52	0.45	0.44	0.72	0.19	1.50	0.09	0.91	0.39	0.41	1.22	
)ITqO	EXAMPLE 1	REFRACTIVE INDEX OF SUBSTRATE	STR	0.11	0.72	0.33	0.54	0.63	0.22	1.55	0.06	0.94	0.37	0.42	1.24	AIR
		LAYER MATERIAL		Hf02	SiO ₂		SiO ₂	HfO ₂	MgF ₂							
		LAYER NUMBER		~	S	3	4	5	9	7	S	റ	10	77	12	

U.S. Patent US 9,423,529 B2 Aug. 23, 2016 Sheet 3 of 26

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n=1

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U.S. Patent Aug. 23, 2016 Sheet 4 of 26 US 9,423,529 B2

Ļ	WAVELENGTH		EXAMPLE 1		Ш Ш	XAMPLE 2			KAMPLE 3	
ń	RANGE	n=1.48	n=1.45	n=1.54	n=1.60	n=1.54	n=1.64	\sim	n=1.65	n=1.80
_	400nm~680nm	0.78	0.78	0.83	0.82	0.82	0.87	0.85	0.86	0.93
()	680nm~1350nm	1.14	1.19	1.10	1.20	1.30	1.15	1.25	1.22	1.17
	400nm~680nm	0.93	1.09	1.11	0.98	1.24	1.23	1.02	1.07	1.45
(0)	680nm~1350nm	1.33	1.39	1.57	1.59	1.66	1.58	1.73	1.73	1.84

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U.S. Patent US 9,423,529 B2 Aug. 23, 2016 Sheet 5 of 26



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ENGTH (nm) WAVEL







U.S. Patent Aug. 23, 2016 Sheet 6 of 26 US 9,423,529 B2



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n=1

U.S. Patent Aug. 23, 2016 Sheet 7 of 26 US 9,423,529 B2



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OPTICAL FILM THICKNESS	E 4 EXAMPLE 5 EXAMPLE 6	/E INDEX REFRACTIVE INDEX REFRACTIVE IND TRATE OF SUBSTRATE OF SUBSTRATI .48 n=1.60 n=1.70	UBSTRATE	18 0.25 0.25	0.34	43 0.53 0.53	34 0.28 0.23	64 0.65	13 0.10 0.08	26		59 0.60 0.61	35	32 0.31 0.32	1.15 1.17	AIR
	EXAN	LAYER MATERIAL OF SUBS n=1.		TiO2	MgF ₂	TiO ₂	MgF ₂	TiO ₂	MgF ₂	TiO ₂	MgF ₂		MgF ₂	TiO ₂	MgF ₂	
		LAYER NUMBER			2	3	4	5	9	2	8	б	10	~ ~	12	

U.S. Patent US 9,423,529 B2 Aug. 23, 2016 Sheet 8 of 26



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U.S. Patent Aug. 23, 2016 Sheet 9 of 26 US 9,423,529 B2

	WAVELENGTH		EXAMPLE 4		ГШ 	XAMPLE 5		Ш	XAMPLE 6	
	RANGE	n=1.48	n=1.45	n=1.54	n=1.60	n=1.54	n=1.64	n=1.70	n=1.65	n=1.80
10/1	400nm~680nm	0.69	0.69	0.75	0.72	0.71	0.76	0.71		0.83
(o/)-	680nm~1350nm	1.05	1.12	0.97	1.05	1.16	1.00	1.05	1.15	0.99
(70/)	400nm~680nm	1.04	1.17	1.23	0.98	1.29	1.12	0.92	1.22	1.30
(\ \)	680nm~1350nm	1.47	1.65	1.33	1.33	1.60	1.32	1.26	1.54	1.57
			22.	22	22.1	20.1	70.1	770	1. 1	

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U.S. Patent US 9,423,529 B2 Aug. 23, 2016 Sheet 10 of 26











U.S. Patent Aug. 23, 2016 Sheet 11 of 26 US 9,423,529 B2







WAVELENGTH (nm)

U.S. Patent US 9,423,529 B2 Aug. 23, 2016 Sheet 12 of 26

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	FICAL FILM I HICKNEVU	7 EXAMPLE 8	EX REFRACTIVE INDEX RE OF SUBSTRATE n=1.60	TRATE	0.20	0.39	0.44	0.41	0.73	0.18	1.46 1.65	0.11 0.	0.70	0	0.39	1.26 1.27	
I I I I I I I I I I I I I I I I I I I	С Г С	LE 7	E INDEX 18 48	μ <u>γ</u>							~		t	8	10		

MgF₂



U.S. Patent Aug. 23, 2016 Sheet 13 of 26 US 9,423,529 B2



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U.S. Patent Aug. 23, 2016 Sheet 14 of 26 US 9,423,529 B2

n=1.48 n=1.45 n=1.60 n=1.54 n=1.65 n=1.65<	AVELENGTH EXAMPLE 7 EXAMPLE 8 EXAMPLE 9		XAMPLE n=1.65 0.74 1.11 1.52	n=1.70 0.75 1.01 1.12	n=1.64 1.39 1.39		23 3 1 1 0 2 0 2 1 0 2 0 2 1 0 2 0 2 0 2 0 2		XAMPLE 7 n=1.45 0.73 0.97 0.98 1.35	13 13 13 148 13 148 13 148 13 148 13 148 13 148 148 148 148 148 148 148 148 148 148	WAVELENGTH RANGE 400nm~680nm 680nm~1350nm 680nm~1350nm 680nm~1350nm
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U.S. Patent Aug. 23, 2016 Sheet 15 of 26 US 9,423,529 B2









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U.S. Patent US 9,423,529 B2 Aug. 23, 2016 Sheet 16 of 26



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REFLECTANCE (%)

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U.S. Patent Aug. 23, 2016 Sheet 17 of 26 US 9,423,529 B2





4	SiO ₂	0.44
5	Ta ₂ O ₅	0.73
6	SiO ₂	0.20
7	Ta ₂ O ₅	1.24
8	SiO ₂	0.15
9	Ta ₂ O ₅	0.82
10	SiO ₂	0.44
11	Ta ₂ O ₅	0.24
12	MgF_2	1.25
	AIR	

U.S. Patent Aug. 23, 2016 Sheet 18 of 26 US 9,423,529 B2





U.S. Patent Aug. 23, 2016 Sheet 19 of 26 US 9,423,529 B2



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-LECTANCE	WAVELENGTH RANGE	EXAMPLE 10	EXAMPLE 11	EXAMPLE 12	Ш Ш
	400nm~680nm	0.93	0.93	0.93	
	680nm~1350nm	0.75	0.79	0.74	
VINALINA/0/ V	400nm~680nm	1.26	1.39	1.30	
	680nm~1350nm	0.97	1.16	0.93	



U.S. Patent US 9,423,529 B2 Aug. 23, 2016 Sheet 20 of 26



FIG. 20

LAYER NUMBER	LAYER MATERIAL	OPTICAL FILM THICKNESS
	SUBSTRATE	
1	HfO ₂	0.15
2	SiO ₂	0.55
3	HfO ₂	0.41
4	SiO ₂	0.46
5	HfO ₂	0.69
6	SiO ₂	0.20
7	HfO ₂	1.54
8	SiO ₂	0.08
9	HfO ₂	0.91
10	SiO ₂	0.38
11	HfO ₂	0.42
12	MgF ₂	1.24
	AIR	

U.S. Patent Aug. 23, 2016 Sheet 21 of 26 US 9,423,529 B2



U.S. Patent US 9,423,529 B2 Aug. 23, 2016 Sheet 22 of 26



FIG. 22

·	LAYER NUMBER	LAYER MATERIAL	OPTICAL FILM THICKNESS
		SUBSTRATE	
	1	TiO ₂	0.15
	2	MgF ₂	0.55
	3	TiO ₂	0.41
	4	MgF ₂	0.46
	5	TiO ₂	0.69
	6	MgF ₂	0.20
	7	TiO ₂	1.54
	8	MgF ₂	0.08
	9	TiO ₂	0.91
	10	MgF ₂	0.38
	11	TiO ₂	0.42
	12	MgF ₂	1.24
		AIR	

U.S. Patent Aug. 23, 2016 Sheet 23 of 26 US 9,423,529 B2



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WAVELENGTH (nm)

U.S. Patent Aug. 23, 2016 Sheet 24 of 26 US 9,423,529 B2



LAYER NUMBER	LAYER MATERIAL	OPTICAL FILM THICKNESS
	SUBSTRATE	
1	Ta ₂ O ₅	0.14
2	SiO ₂	0.67
3	Ta ₂ O ₅	0.41
4	SiO ₂	0.44
5	Ta ₂ O ₅	0.73
6	SiO ₂	0.20
7	Ta ₂ O ₅	1.24
8	SiO ₂	0.15
9	Ta ₂ O ₅	0.82
10	SiO ₂	0.44
11	Ta2O ₅	0.36
12	MgF ₂	1.25
13	SiO ₂	0.03
	AIR	

U.S. Patent Aug. 23, 2016 Sheet 25 of 26 US 9,423,529 B2



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U.S. Patent Aug. 23, 2016 Sheet 26 of 26 US 9,423,529 B2





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ANTIREFLECTION COATING, OPTICAL SYSTEM, AND OPTICAL INSTRUMENT

CROSS-REFERENCE TO RELATED APPLICATION

The present application is based upon and claims the benefit of priority from the prior Japanese Patent Application No. 2011-130083 filed on Jun. 10, 2011; the entire contents of which are incorporated herein by reference.

TECHNICAL FIELD

The present invention relates to an antireflection coating,

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Patent Literature 2: Japanese Patent Application Laid-Open No. 9-325211

Patent Literature 3: Japanese Patent Application Laid-Open No. 2005-338366

Non Patent Literature

Non-patent Literature 1: H. A. Macleod, 'Thin Film Optical Filters' Pages 129-130, December, 1989, Nikkan Kogyo Shinbunsha Shuppan 10

SUMMARY OF INVENTION

an optical system having the antireflection coating, and an 15 optical instrument having the optical system.

BACKGROUND ART

In recent years, applications of fluorescence microscopes have been increasing in the field of medical care and $_{20}$ chemistry. In the fluorescence microscopes, by giving a reagent containing a fluorescent protein to an object to be observed and irradiating the object with light of a certain wavelength, fluorescent light having a different wavelength is emitted from the reagent and the fluorescent light is used for observations of cells etc. As an example of such a fluorescence microscope, a multiphoton absorption microscope is named.

The multiphoton absorption microscope uses high order, e.g. second order, of laser beam as excitation light in order to achieve high power output. Thus, the wavelength of laser beam is in the infrared range for visible light observation by the excitation.

Therefore, it is necessary for an optical system in the multiphoton absorption microscope to transmit fluorescent light (visible light) for observation as well as near infrared 35 light of excitation laser beam for generating the fluorescent light. For this reason, an antireflection coating able to transmit from visible light to near infrared light is needed. As the excitation light, light having a wavelength approximately twice of the fluorescent observation wavelength is 40 needed. In fluorescent observation, the wavelength used for observation is determined by the reagent used. Since the wavelength used for observation is approximately 500 nm, it is required for the optical system to transmit light in the wavelength range up to near infrared (approximately 1000 45 nm). Commonly known antireflection coatings are adapted to transmit visible light (in the wavelength range of 400 nm to 680 nm). Non-patent literature 1 describes a design of a three-layer antireflection coating. Patent literature 1 dis- 50 closes an antireflection coating for near infrared light not including visible light. In cases where visible light is used, light in the near infrared wavelength range is blocked in many cases. For this reason, an antireflection coating that transmits visible light and reflects near infrared light has been proposed as disclosed in patent literature 2. As an antireflection coating for visible light and near infrared light, an antireflection coating that transmits light in the wavelength range of 400 nm to 1100 nm is disclosed in patent literature 3.

Technical Problem

By development of new reagents adapted to objects to be observed, the wavelength range that can be used in fluorescent observation is being extended to cover the entire visible wavelength range. To enable fluorescent observation throughout the entire visible wavelength range, an optical system that can transmit visible light (from 400 nm to 680 nm) and excitation laser light (from 800 nm to 1350 nm) is needed. In other words, the optical system needs to have a transmission band ranging from 400 nm to 1350 nm, namely a transmission band having a width almost twice as large as the width of the visible light wavelength range.

FIG. 26 is a diagram showing the basic construction of a conventional multiphoton absorption microscope.

In the multiphoton absorption microscope shown in FIG. 26, short pulse laser light generated by a laser source 501 is reflected by a multi-layer filter 502 and delivered to an object S to be observed set on an observation table 503. Light generated in the object S to be observed by irradiation with the laser light is transmitted through the multi-layer filter 502 to allow observation by an observer B. It is required for the multi-layer filter 502, in its characteristics, to transmit light generated in the object S to be observed to allow observation in the visible wavelength range, and not to cause an increase in the pulse width in a reflection band which includes the wavelength of the short pulse laser light. In the multiphoton absorption microscope shown in FIG. 26, it is necessary that the objective lens for observation have an antireflection coating for the wavelength range of 400 nm to 1350 nm. It is desirable that the antireflection coating be able to transmit light having a wavelength up to 1600 nm, taking into consideration peripheral applications used to facilitate observation. However, antireflection coatings disclosed in non-patent literature 1 and patent literature 1 can transmit only one of visible light and near infrared light. On the other hand, the width of the transmission band of the antireflection coating disclosed in patent literature 3 is not large enough, and its reflectance is 7% at wavelength of 1350 nm and 16% at wavelength of 1600 nm, which are higher than the reflectance of the lens and the substrate. Therefore, it cannot serve as an antireflection coating. The present invention has been made in view of the above-described problems, and an object of the present invention is to provide an antireflection coating having an effective antireflection band at least ranging from visible ⁶⁰ light to near infrared light (wavelength range of 400 nm to 1350 nm).

CITATION LIST

Solution to Problem

Patent Literature

Patent Literature 1: Japanese Patent Application Laid-Open No. 2005-275294

To solve the above problems and to achieve the object, 65 there is provided according to the present invention an antireflection coating characterized by comprising an depos-

3

ited structure made up of twelve layers in which layers of a high refractive index material having a refractive index nH of 1.95 to 2.32 and layers of a low refractive index material having a refractive index of 1.35 to 1.46 are deposited alternately, wherein the reflectance of the antireflection coating is not higher than 1.5% in the wavelength range of 400 nm to 680 nm and not higher than 2.0% in the wavelength range of 680 nm to 1350 nm.

In the antireflection coating according to the present invention, it is preferred that the high refractive index layers be arranged as first, third, fifth, seventh, ninth, and eleventh layers, the low refractive index layers be arranged as second, fourth, sixth, eighth, tenth, and twelfth layers, where the layers are numbered in order from the side of a substrate on 15 ing to examples 4, 5, and 6; which the deposited structure is formed, and the optical layer thickness, which is defined as the product of the refractive index and the physical film thickness d, of layers in the deposited structure satisfy the following conditions respectively: 1st layer: 0.11<nHd<0.25, 2nd layer: 0.33<nLd<0.72, 3rd layer: 0.33<nHd<0.60, 4th layer: 0.23<nLd<0.54, 5th layer: 0.63<nHd<0.88, 6th layer: 0.08<nLd<0.22, 7th layer: 1.23<nHd<2.29, 8th layer: 0.06<nLd<0.15, 9th layer: 0.59<nHd<0.94, 10th layer: 0.34<nLd<0.44, 11th layer: 0.23 < nHd < 0.42, and 12th layer: 1.15<nLd<1.27. In the antireflection coating according to the present invention, it is preferred that the high refractive index $_{35}$ material be TiO₂, Nb₂O₅, Ta₂O₅, HfO₂, or a mixture of these materials with La and/or Zr, and the low refractive index material be SiO_2 , MgF_2 , or a mixture of SiO_2 and MgF_2 . In the antireflection coating according to the present invention, it is preferred that the refractive index of the $_{40}$ substrate be in the range from 1.48 to 1.8. An optical system according to the present invention comprises two or more substrates on which an antireflection coating according to the present invention is formed. An optical instrument according to the present invention 45 comprises an optical system according to the present invention.

FIG. 4 is a table showing the average reflectance and the maximum reflectance of the antireflection coatings according to examples 1, 2, and 3;

FIG. 5 is a graph showing reflectance characteristics of the antireflection coating according to example 2; FIG. 6 is a graph showing reflectance characteristics of

the antireflection coating according to example 3;

FIG. 7 is a table showing specifications of the layer structure of antireflection coatings according to examples 4, 10 5, and 6;

FIG. 8 is a graph showing reflectance characteristics of the antireflection coating according to example 4; FIG. 9 is a table showing the average reflectance and the

maximum reflectance of the antireflection coatings accord-

FIG. 10 is a graph showing reflectance characteristics of the antireflection coating according to example 5;

FIG. 11 is a graph showing reflectance characteristics of the antireflection coating according to example 6;

FIG. 12 is a table showing specifications of the layer 20 structure of antireflection coatings according to examples 7, 8, and 9;

FIG. 13 is a graph showing reflectance characteristics of the antireflection coating according to example 7;

FIG. 14 is a table showing the average reflectance and the 25 maximum reflectance of the antireflection coatings according to examples 7, 8 and 9;

FIG. 15 is a graph showing reflectance characteristics of the antireflection coating according to example 8;

FIG. 16 is a graph showing reflectance characteristics of 30 the antireflection coating according to example 9; FIG. 17 is a table showing specifications of the layer structure of an antireflection coating according to example 10;

FIG. 18 is a graph showing reflectance characteristics of the antireflection coating according to example 10;

Advantageous Effects of Invention

The antireflection coating according to the present invention is advantageous in enabling to provide an optical system transmitting visible light and excitation light having a wavelength approximately twice as long as the wavelength of the visible light, thereby enabling a fluorescent observation over 55 the entire visible wavelength range.

FIG. **19** is a table showing the average reflectance and the maximum reflectance of the antireflection coatings according to examples 10, 11, 12 and 13;

FIG. 20 is a table showing specifications of the layer structure of the antireflection coating according to example 11;

FIG. 21 is a graph showing reflectance characteristics of the antireflection coating according to example 11;

FIG. 22 is a table showing specifications of the layer structure of the antireflection coating according to example 12;

FIG. 23 is a graph showing reflectance characteristics of the antireflection coating according to example 12; FIG. 24 is a table showing specifications of the layer 50 structure of the antireflection coating according to example 13;

FIG. 25 is a graph showing reflectance characteristics of the antireflection coating according to example 13; and FIG. 26 is a diagram showing the basic construction of a conventional multiphoton absorption microscope.

BRIEF DESCRIPTION OF DRAWINGS

DESCRIPTION OF EMBODIMENTS

FIG. 1 is a diagram showing the basic construction of a 60 multiphoton absorption microscope according to an embodiment of the present invention;

FIG. 2 is a table showing specifications of the layer structure of antireflection coatings according to examples 1, 2, and 3; 65

FIG. 3 is a graph showing reflectance characteristics of the antireflection coating according to example 1;

In the following, embodiments of the antireflection coating, optical system, and optical instrument according to the present invention will be described in detail with reference to the drawings. The present invention is not limited by the embodiments described in the following. FIG. 1 is a diagram showing the basic construction of a multiphoton absorption microscope as an embodiment of the

optical instrument according to the present invention.

5

In the multiphoton absorption microscope shown in FIG. 1, short pulse laser light generated by a laser source 101 is reflected by a multi-layer filter 102 and delivered to an objects S to be observed set on an observation table 103 through an optical system 110 having an antireflection ⁵ coating according to the embodiment. Light generated in the object S to be observed by irradiation with the laser light is transmitted through the multi-layer filter 102 to allow observation by an observer B.

Next, the construction, operation, and advantageous ¹⁰ effects of the antireflection coating in this embodiment will be described. The antireflection coating in this embodiment is characterized in having a reflectance not higher than 1.5% in the wavelength range of 400 nm to 680 nm and not higher $_{15}$ than 2.0% in the wavelength range of 680 nm to 1350 nm. With this antireflection coating, it is possible to provide an optical system that transmits visible light and excitation light having a wavelength twice as long as that of the visible light, enabling fluorescent observation over the entire visible 20 wavelength range. Since the intensity of light generated in the visible wavelength range (wavelength range of 400 nm to 680 nm) is low, it is preferred that the reflectance be not higher than 1.5%, more preferably not higher than 1%, in order to make the 25 loss of transmitted light as small as possible. On the other hand, the intensity of the laser light in the wavelength range of 680 nm to 1350 nm used as the excitation light is very high, it is preferred for an appropriate antireflection effect that the reflectance be not higher than 30 5%, more preferably no higher than 2%, still more preferably not higher than 1.5%. The antireflection coating according to this embodiment has a deposition structure made up of twelve layers in which layers of a high refractive index material having an refrac- 35 tive index nH in the range of 1.95 to 2.32 and layers of a low refractive index material having a refractive index nL in the range of 1.35 to 1.46 are deposited alternately. The first, third, fifth, seventh, ninth, and eleventh layers are high refractive index layers, and the second, fourth, sixth, eighth, 40 tenth, and twelfth layers are low refractive index layers, where the layers are numbered in order from the side of a substrate on which the deposited structure is formed. It is preferred that the optical layer thickness, which is defined as the product of the refractive index and the physical thickness 45 D, of the layers in the deposited structure satisfy the following conditions respectively: 1st layer: 0.11<nHd<0.25, 2nd layer: 0.33<nLd<0.72, 3rd layer: 0.33<nHd<0.60, 4th layer: 0.23<nLd<0.54, 5th layer: 0.63<nHd<0.88, 6th layer: 0.08<nLd<0.22, 7th layer: 1.23<nHd<2.29, 8th layer: 0.06<nLd<0.15, 9th layer: 0.59<nHd<0.94, 10th layer: 0.34<nLd<0.44, 11th layer: 0.23 < nHd < 0.42, and 12th layer: 1.15<nLd<1.27. In the antireflection coating according to this embodi- 60 ment, it is preferred that the high refractive index material be TiO₂, Nb₂O₅, Ta₂O₅, HfO₂, or a mixture of these materials with La and/or Zr and that the low refractive index material be SiO_2 , MgF_2 , or a mixture of SiO_2 and MgF_2 . In the antireflection coating according to this embodi- 65 ment, it is preferred that the refractive index of the substrate be in the range of 1.48 to 1.8.

6

The optical system according to this embodiment is characterized by including two or more substrates on which the antireflection coating according to the embodiment is formed.

The optical instrument according to the embodiment is characterized by including the above-described optical system according to the embodiment.

It is not necessary that each of the high refractive index material and the low refractive index material be one kind of material. For example, the second layer and the fourth layer may be made of low refractive index materials different in kind from each other. The coating method may be, but not limited to, vacuum deposition, IAD, plasma assisted deposition, sputtering, ion beam sputtering, spin coating, or dipping. It is preferred that the antireflection coating according to the embodiment be applied on an objective lens of a microscope, but it can also be applied to lenses, prism, or filers of cameras, eyeglasses, and telescopes etc. The optical instrument according to the embodiment of the present invention is, for example, one of these optical instruments listed above, and the optical system according to the embodiment is, for example, the optical system with which one of these instruments is equipped.

Examples 1 to 3

FIG. 2 is a table showing specifications of the layer structure of antireflection coatings according to examples 1, 2, and 3. FIG. 3 is a graph showing reflectance characteristics of the antireflection coating according to example 1. FIG. 4 is a table showing the average reflectance and the maximum reflectance of the antireflection coatings according to examples 1, 2, and 3. FIG. 5 is a graph showing reflectance characteristics of the antireflection coating according to example 2. FIG. 6 is a graph showing reflectance characteristics of the antireflection coating according to example 3. FIG. 2 shows the optical layer thickness of the layers. In FIG. 3, the broken curve, the dotted curve, and the solid curve represent the reflectance in cases where the refractive index n of the substrate is 1.48, 1.45, and 1.54 respectively. In FIG. 5, the broken curve, the dotted curve, and the solid curve represent the reflectance in cases where the refractive index n of the substrate is 1.60, 1.54, and 1.64 respectively. In FIG. 6, the broken curve, the dotted curve, and the solid curve represent the reflectance in cases where the refractive index n of the substrate is 1.70, 1.65, and 1.80 respectively. 50 FIG. 4 shows the average reflectance and the maximum reflectance with the substrates mentioned above in connection with FIGS. 3, 5, and 6.

As shown in FIG. 2, the antireflection coatings according to examples 1 to 3 have a deposition structure made up of

55 twelve layers in which layers of HfO_2 (having a refractive index nH of 1.99) as a high refractive index material and layers of SiO₂ (having a refractive index nL of 1.45) or

MgF₂ (having a refractive index nL of 1.45) of MgF₂ (having a refractive index nL of 1.38) as a low refractive index material are deposited alternately. The layers of HfO₂ as a high refractive index material are arranged as the first, third, fifth, seventh, ninth, and eleventh layers. Here, the layers are numbered in order from the side of the substrate. The layers of SiO₂ as a low refractive index material are arranged as the second, fourth, sixth, eighth, and tenth layers. The layer of MgF₂ as a low refractive index material is arranged as the twelfth layer (the outermost layer).

10

7

The optical layer thickness, which is defined as the product of the refractive index nH, nL and the physical thickness D, of the each layers in the deposition structure satisfies the following conditions respectively. Here, the optical layer thickness is expressed in a unit where a quarter ⁵ of design wavelength is expressed as 1.00 at the design wavelength of 550 nm.

1st layer: 0.11<nHd<0.25, 2nd layer: 0.33<nLd<0.72, 3rd layer: 0.33<nHd<0.60, 4th layer: 0.23<nLd<0.54, 5th layer: 0.63<nHd<0.88, 6th layer: 0.08<nLd<0.22,

8

maximum reflectance is 1.66% and the average reflectance
is 1.30% in the wavelength range of 680 nm to 1350 nm.
In the case where the antireflection coating is formed on
a substrate having a refractive index of 1.64, the maximum
reflectance is 1.23% and the average reflectance is 0.87% in
the wavelength range of 400 nm to 680 nm, and the
maximum reflectance is 1.58% and the average reflectance
is 1.15% in the wavelength range of 680 nm to 1350 nm.

Example 3

As shown in FIGS. **4** and **6**, the antireflection coating according to example 3 has a reflectance lower than 1.5% in the wavelength range of 400 nm to 680 nm and lower than 15 2.0% in the wavelength range of 680 nm to 1350 nm, with any substrate having a refractive index falling in the range of 1.65 to 1.80.

7th layer: 1.23<nHd<2.29, 8th layer: 0.06<nLd<0.15, 9th layer: 0.59<nHd<0.94, 10th layer: 0.34<nLd<0.44, 11th layer: 0.23<nHd<0.42, 12th layer: 1.15<nLd<1.27.

Example 1

As shown in FIGS. **3** and **4**, the antireflection coating according to example 1 has a reflectance lower than 1.5% in the wavelength range of 400 nm to 680 nm and lower than ²⁵ 2.0% in the wavelength range of 680 nm to 1350 nm, with any substrate having a refractive index falling in the range of 1.45 to 1.54.

Specifically, as shown in FIG. 4, in the case where the antireflection coating is formed on a substrate having a 30 refractive index of 1.48, the maximum reflectance is 0.93% and the average reflectance is 0.78% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.33% and the average reflectance is 1.15% in the wavelength range of 680 nm to 1350 nm. In the case where the antireflection coating is formed on a substrate having a refractive index of 1.45, the maximum reflectance is 1.09% and the average reflectance is 0.78% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.39% and the average reflectance 40 is 1.19% in the wavelength range of 680 nm to 1350 nm. In the case where the antireflection coating is formed on a substrate having a refractive index of 1.54, the maximum reflectance is 1.11% and the average reflectance is 0.83% in the wavelength range of 400 nm to 680 nm, and the 45 maximum reflectance is 1.57% and the average reflectance is 1.11% in the wavelength range of 680 nm to 1350 nm.

Specifically, as shown in FIG. **4**, in the case where the antireflection coating is formed on a substrate having a refractive index of 1.70, the maximum reflectance is 1.02% and the average reflectance is 0.85% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.73% and the average reflectance is 1.25% in the wavelength range of 680 nm to 1350 nm.

In the case where the antireflection coating is formed on a substrate having a refractive index of 1.65, the maximum reflectance is 1.07% and the average reflectance is 0.86% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.73% and the average reflectance is 1.22% in the wavelength range of 680 nm to 1350 nm.

In the case where the antireflection coating is formed on a substrate having a refractive index of 1.80, the maximum reflectance is 1.45% and the average reflectance is 0.93% in the wavelength range of 400 nm to 680 nm, and the 35 maximum reflectance is 1.84% and the average reflectance is 1.17% in the wavelength range of 680 nm to 1350 nm.

Example 2

As shown in FIGS. **4** and **5**, the antireflection coating according to example 2 has a reflectance lower than 1.5% in the wavelength range of 400 nm to 680 nm and lower than 2.0% in the wavelength range of 680 nm to 1350 nm, with any substrate having a refractive index falling in the range 55 of 1.54 to 1.64.

Specifically, as shown in FIG. **4**, in the case where the antireflection coating is formed on a substrate having a refractive index of 1.60, the maximum reflectance is 0.98% and the average reflectance is 0.82% in the wavelength range 60 of 400 nm to 680 nm, and the maximum reflectance is 1.59% and the average reflectance is 1.20% in the wavelength range of 680 nm to 1350 nm. In the case where the antireflection coating is formed on a substrate having a refractive index of 1.54, the maximum 65 reflectance is 1.24% and the average reflectance is 0.82% in the wavelength range of 400 nm to 680 nm, and the average reflectance is 0.82% in the wavelength range of 400 nm to 680 nm, and the average reflectance is 0.82% in the wavelength range of 400 nm to 680 nm, and the average reflectance is 0.82% in the wavelength range of 400 nm to 680 nm, and the average reflectance is 0.82% in the wavelength range of 400 nm to 680 nm, and the average reflectance is 0.82% in the wavelength range of 400 nm to 680 nm, and the average reflectance is 0.82% in the wavelength range of 400 nm to 680 nm, and the average reflectance is 0.82% in the wavelength range of 400 nm to 680 nm, and the

Examples 4 to 6

FIG. 7 is a table showing specifications of the layer structure of antireflection coatings according to examples 4, 5, and 6. FIG. 8 is a graph showing reflectance characteristics of the antireflection coating according to example 4. FIG. 9 is a table showing the average reflectance and the maximum reflectance of the antireflection coatings according to examples 4, 5, and 6. FIG. 10 is a graph showing reflectance characteristics of the antireflection coating according to example 5. FIG. 11 is a graph showing reflectance characteristics of the antireflection coating according to example 5. FIG. 11 is a graph showing reflectance characteristics of the antireflection coating according to example 6.

FIG. 7 shows the optical layer thickness of the each layers. In FIG. 8, the broken curve, the dotted curve, and the solid curve represent the reflectance in cases where the refractive index n of the substrate is 1.48, 1.45, and 1.54 respectively. In FIG. 10, the broken curve, the dotted curve, and the solid curve represent the reflectance in cases where the refractive index n of the substrate is 1.60, 1.54, and 1.64 respectively. In FIG. 11, the broken curve, the dotted curve, and the solid curve represent the reflectance in cases where the refractive index n of the substrate is 1.70, 1.65, and 1.80 respectively. FIG. 9 shows the average reflectance and the maximum reflectance with the substrates mentioned above in connection with FIGS. 8, 10, and 11. As shown in FIG. 7, the antireflection coatings according to examples 4 to 6 have a deposition structure made up of twelve layers in which layers of TiO₂ (having a refractive index nil of 2.22) as a high refractive index material and

9

layers of MgF₂ (having a refractive index nL of 1.38) as a low refractive index material are deposited alternately. The layers of TiO₂ as a high refractive index material are arranged as the first, third, fifth, seventh, ninth, and eleventh layers. Here, the layers are numbered in order from the side 5 of the substrate. The layers of MgF₂ as a low refractive index material are arranged as the second, fourth, sixth, eighth, tenth, and twelfth layers.

The optical layer thickness, which is defined as the product of the refractive index nH, nL and the physical ¹⁰ thickness D, of the layers in the deposition structure satisfies the following conditions respectively. Here, the optical layer thickness is expressed in a unit where a quarter of design

10

and the average reflectance is 0.72% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.33% and the average reflectance is 1.05% in the wavelength range of 680 nm to 1350 nm.

In the case where the antireflection coating is formed on a substrate having a refractive index of 1.54, the maximum reflectance is 1.29% and the average reflectance is 0.71% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.60% and the average reflectance is 1.16% in the wavelength range of 680 nm to 1350 nm. In the case where the antireflection coating is formed on a substrate having a refractive index of 1.64, the maximum reflectance is 1.12% and the average reflectance is 0.76% in

wavelength is expressed as 1.00 at the design wavelength of 550 nm.

1st layer: 0.11<nHd<0.25, 2nd layer: 0.33<nLd<0.72, 3rd layer: 0.33<nHd<0.60, 4th layer: 0.23<nLd<0.54, 5th layer: 0.63<nHd<0.88, 6th layer: 0.08<nLd<0.22, 7th layer: 1.23<nHd<2.29, 8th layer: 0.06<nLd<0.15, 9th layer: 0.59<nHd<0.94, 10th layer: 0.34<nLd<0.44, 11th layer: 0.23<nHd<0.42, 12th layer: 1.15<nLd<1.27.

Example 4

As shown in FIGS. 8 and 9, the antireflection coating according to example 4 has a reflectance lower than 1.5% in the wavelength range of 400 nm to 680 nm and lower than 2.0% in the wavelength range of 680 nm to 1350 nm, with any substrate having a refractive index falling in the range 35 of 1.45 to 1.54. Specifically, as shown in FIG. 9, in the case where the antireflection coating is formed on a substrate having a refractive index of 1.48, the maximum reflectance is 1.04% and the average reflectance is 0.69% in the wavelength range 40 of 400 nm to 680 nm, and the maximum reflectance is 1.47% and the average reflectance is 1.05% in the wavelength range of 680 nm to 1350 nm. In the case where the antireflection coating is formed on a substrate having a refractive index of 1.45, the maximum 45 reflectance is 1.17% and the average reflectance is 0.69% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.65% and the average reflectance is 1.12% in the wavelength range of 680 nm to 1350 nm. In the case where the antireflection coating is formed on 50 a substrate having a refractive index of 1.54, the maximum reflectance is 1.23% and the average reflectance is 0.75% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.33% and the average reflectance is 0.97% in the wavelength range of 680 nm to 1350 nm.

the wavelength range of 400 nm to 680 nm, and the ¹⁵ maximum reflectance is 1.32% and the average reflectance is 1.00% in the wavelength range of 680 nm to 1350 nm.

Example 6

As shown in FIGS. 9 and 11, the antireflection coating 20 according to example 6 has a reflectance lower than 1.5% in the wavelength range of 400 nm to 680 nm and lower than 2.0% in the wavelength range of 680 nm to 1350 nm, with any substrate having a refractive index falling in the range 25 of 1.65 to 1.80.

Specifically, as shown in FIG. 9, in the case where the antireflection coating is formed on a substrate having a refractive index of 1.70, the maximum reflectance is 0.92% and the average reflectance is 0.71% in the wavelength range ³⁰ of 400 nm to 680 nm, and the maximum reflectance is 1.26% and the average reflectance is 1.05% in the wavelength range of 680 nm to 1350 nm.

In the case where the antireflection coating is formed on a substrate having a refractive index of 1.65, the maximum reflectance is 1.22% and the average reflectance is 0.70% in

Example 5

the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.54% and the average reflectance is 1.15% in the wavelength range of 680 nm to 1350 nm. In the case where the antireflection coating is formed on a substrate having a refractive index of 1.80, the maximum reflectance is 1.30% and the average reflectance is 0.83% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.57% and the average reflectance is 0.99% in the wavelength range of 680 nm to 1350 nm.

Examples 7 to 9

FIG. 12 is a table showing specifications of the layer structure of antireflection coatings according to examples 7, 8, and 9. FIG. 13 is a graph showing reflectance characteristics of the antireflection coating according to example 7. FIG. 14 is a table showing the average reflectance and the maximum reflectance of the antireflection coatings according to examples 7, 8 and 9. FIG. 15 is a graph showing reflectance characteristics of the antireflection coating according to example 8. FIG. 16 is a graph showing reflectance characteristics of the antireflection coating according to example 9.

As shown in FIGS. 9 and 10, the antireflection coating according to example 5 has a reflectance lower than 1.5% in 60 the wavelength range of 400 nm to 680 nm and lower than 2.0% in the wavelength range of 680 nm to 1350 nm, with any substrate having a refractive index falling in the range of 1.54 to 1.64.

Specifically, as shown in FIG. 9, in the case where the 65 antireflection coating is formed on a substrate having a refractive index of 1.60, the maximum reflectance is 0.98%

FIG. 12 shows the optical layer thickness of the layers. In FIG. 33, the broken curve, the dotted curve, and the solid curve represent the reflectance in cases where the refractive index n of the substrate is 1.48, 1.45, and 1.54 respectively. In FIG. 15, the broken curve, the dotted curve, and the solid curve represent the reflectance in cases where the refractive index n of the substrate is 1.60, 1.54, and 1.64 respectively. In FIG. 16, the broken curve, the dotted curve, and the solid curve represent the reflectance in cases where the refractive

11

index n of the substrate is 1.70, 1.65, and 1.80 respectively. FIG. 14 shows the average reflectance and the maximum reflectance with the substrates mentioned above in connection with FIGS. 13, 15, and 16.

As shown in FIG. 12, the antireflection coatings according 5to examples 7 to 9 have a deposition structure made up of twelve layers in which layers of Ta_2O_5 (having a refractive index nH of 2.22) as a high refractive index material and layers of SiO₂ (having a refractive index nL of 1.45) or MgF₂ (having a refractive index nL of 1.38) as a low refractive index material are deposited alternately. The layers of Ta_2O_5 as a high refractive index material are arranged as the first, third, fifth, seventh, ninth, and eleventh layers. Here, the layers are numbered in order from the side of the substrate. The layers of SiO₂ as a low refractive index material are arranged as the second, fourth, sixth, eighth, and 15tenth layers. The layer of MgF₂ as a low refractive index material is arranged as the twelfth layer. The optical layer thickness, which is defined as the product of the refractive index nil, nL and the physical thickness D, of the layers in the deposition structure satisfies 20 the following conditions respectively. Here, the optical layer thickness is expressed in a unit where a quarter of design wavelength is expressed as 1.00 at the design wavelength of 550 nm. 1st layer: 0.11 < nHd < 0.25, 25 2nd layer: 0.33<nLd<0.72, 3rd layer: 0.33<nHd<0.60, 4th layer: 0.23<nLd<0.54, 5th layer: 0.63<nHd<0.88, 6th layer: 0.08<nLd<0.22, 7th layer: 1.23<nHd<2.29, 8th layer: 0.06<nLd<0.15, 9th layer: 0.59<nHd<0.94, 10th layer: 0.34<nLd<0.44, 11th layer: 0.23<nHd<0.42, 12th layer: 1.15<nLd<1.27.

12

the wavelength range of 400 nm to 680 nm and lower than 2.0% in the wavelength range of 680 nm to 1350 nm, with any substrate having a refractive index falling in the range of 1.54 to 1.64.

Specifically, as shown in FIG. 14, in the case where the antireflection coating is formed on a substrate having a refractive index of 1.60, the maximum reflectance is 1.11% and the average reflectance is 0.82% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.23% and the average reflectance is 1.01% in the wavelength range of 680 nm to 1350 nm.

In the case where the antireflection coating is formed on a substrate having a refractive index of 1.54, the maximum reflectance is 1.22% and the average reflectance is 0.81% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.63% and the average reflectance is 1.10% in the wavelength range of 680 nm to 1350 nm. In the case where the antireflection coating is formed on a substrate having a refractive index of 1.64, the maximum reflectance is 1.15% and the average reflectance is 0.87% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.39% and the average reflectance is 0.99% in the wavelength range of 680 nm to 1350 nm.

Example 9

As shown in FIGS. 14 and 16, the antireflection coating according to example 9 has a reflectance lower than 1.5% in the wavelength range of 400 nm to 680 nm and lower than ³⁰ 2.0% in the wavelength range of 680 nm to 1350 nm, with any substrate having a refractive index falling in the range of 1.65 to 1.80.

Specifically, as shown in FIG. 14, in the case where the antireflection coating is formed on a substrate having a ³⁵ refractive index of 1.70, the maximum reflectance is 1.01%

Example 7

As shown in FIGS. 13 and 14, the antireflection coating according to example 7 has a reflectance lower than 1.5% in $_{40}$ the wavelength range of 400 nm to 680 nm and lower than 2.0% in the wavelength range of 680 nm to 1350 nm, with any substrate having a refractive index falling in the range of 1.45 to 1.54.

antireflection coating is formed on a substrate having a refractive index of 1.48, the maximum reflectance is 0.97% and the average reflectance is 0.75% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.13% and the average reflectance is 0.92% in the wavelength range of 680 nm to 1350 nm.

In the case where the antireflection coating is formed on a substrate having a refractive index of 1.45, the maximum reflectance is 0.98% and the average reflectance is 0.73% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.35% and the average reflectance 55 is 0.97% in the wavelength range of 680 nm to 1350 nm. In the case where the antireflection coating is formed on a substrate having a refractive index of 1.54, the maximum reflectance is 1.31% and the average reflectance is 0.83% in the wavelength range of 400 nm to 680 nm, and the 60 maximum reflectance is 1.23% and the average reflectance is 0.87% in the wavelength range of 680 nm to 1350 nm.

and the average reflectance is 0.75% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.12% and the average reflectance is 0.91% in the wavelength range of 680 nm to 1350 nm.

In the case where the antireflection coating is formed on a substrate having a refractive index of 1.65, the maximum reflectance is 1.11% and the average reflectance is 0.74% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.52% and the average reflectance Specifically, as shown in FIG. 14, in the case where the $_{45}$ is 0.99% in the wavelength range of 680 nm to 1350 nm. In the case where the antireflection coating is formed on a substrate having a refractive index of 1.80, the maximum reflectance is 1.28% and the average reflectance is 0.87% in the wavelength range of 400 nm to 680 nm, and the maximum reflectance is 1.49% and the average reflectance is 0.88% in the wavelength range of 680 nm to 1350 nm.

Examples 10 to 13

FIG. 17 is a table showing specifications of the layer structure of an antireflection coating according to example 10. FIG. 18 is a graph showing reflectance characteristics of the antireflection coating according to example 10. FIG. 19 is a table showing the average reflectance and the maximum reflectance of the antireflection coatings according to examples 10, 11, 12 and 13. FIG. 20 is a table showing specifications of the layer structure of the antireflection coating according to example 11. FIG. **21** is a graph showing reflectance characteristics of the antireflection coating 65 according to example 11. FIG. 22 is a table showing specifications of the layer structure of the antireflection coating according to example 12. FIG. 23 is a graph showing

Example 8

As shown in FIGS. 14 and 15, the antireflection coating according to example 8 has a reflectance lower than 1.5% in

13

reflectance characteristics of the antireflection coating according to example 12. FIG. 24 is a table showing specifications of the layer structure of the antireflection coating according to example 13. FIG. 25 is a graph showing reflectance characteristics of the antireflection coating 5 according to example 13.

FIGS. 17, 20, 22, and 24 show the optical layer thickness of the layers.

FIG. 19 shows the average reflectance and the maximum reflectance of the antireflection coatings according to 10examples 10 to 13.

The optical layer thickness, which is defined as the product of the refractive index nH, nL and the physical

14

refractive index material are arranged as the first, third, fifth, seventh, ninth, and eleventh layers. Here, the layers are numbered in order from the side of the substrate. The layers of SiO₂ as a low refractive index material are arranged as the second, fourth, sixth, eighth, and tenth layers. The layer of MgF₂ as a low refractive index material is arranged as the twelfth layer (the outermost layer).

As shown in FIGS. 19 and 21, in the wavelength range of 400 nm to 680 nm, the antireflection coating according to example 11 has a reflectance of 1.39% at the maximum and 0.93% on an average, which is lower than 1.5%, and in the wavelength range of 680 nm to 1350 nm, the antireflection coating according to example 11 has a reflectance of 1.16%

thickness D, of the layers in the deposition structure satisfies the following conditions respectively. Here, the optical layer 15 reflectance characteristic lower than 2.0%. thickness is expressed in a unit where a quarter of design wavelength is expressed as 1.00 at the design wavelength of 550 nm.

1st layer: 0.11<nHd<0.25, 2nd layer: 0.33<nLd<0.72, 3rd layer: 0.33<nHd<0.60, 4th layer: 0.23<nLd<0.54, 5th layer: 0.63<nHd<0.88, 6th layer: 0.08<nLd<0.22, 7th layer: 1.23<nHd<2.29, 8th layer: 0.06<nLd<0.15, 9th layer: 0.59<nHd<0.94, 10th layer: 0.34<nLd<0.44, 11th layer: 0.23<nHd<0.42, 12th layer: 1.15<nLd<1.27.

Example 10

As shown in FIG. 17, the antireflection coating according to example 10 has a deposition structure made up of twelve ³⁵

at the maximum and 0.79% on an average, showing a

Example 12

As shown in FIG. 22, the antireflection coating according ²⁰ to example 12 has a deposition structure made up of twelve layers in which layers of TiO₂ (having a refractive index nH of 2.32) as a high refractive index material and layers of MgF₂ (having a refractive index nL of 1.38) as a low refractive index material are deposited alternately on a ²⁵ substrate having a refractive index of 1.57. The layers of TiO₂ as a high refractive index material are arranged as the first, third, fifth, seventh, ninth, and eleventh layers. Here, the layers are numbered in order from the side of the substrate. The layers of MgF₂ as a low refractive index ³⁰ material is arranged as the second, fourth, sixth, eighth, tenth, and twelfth (outermost) layers.

As shown in FIGS. 19 and 21, in the wavelength range of 400 nm to 680 nm, the antireflection coating according to example 12 has a reflectance of 1.30% at the maximum and 0.93% on an average, which is lower than 1.5%, and in the wavelength range of 680 nm to 1350 nm, the antireflection coating according to example 12 has a reflectance of 0.93% at the maximum and 0.74% on an average, showing a reflectance characteristic lower than 2.0%.

layers in which layers of Ta_2O_5 (having a refractive index nH of 2.22) as a high refractive index material and layers of SiO₂ (having a refractive index nL of 1.45) or MgF₂ (having a refractive index nL of 1.38) as a low refractive index material are deposited alternately on a substrate having a 40 refractive index of 1.49. The layers of Ta_2O_5 as a high refractive index material are arranged as the first, third, fifth, seventh, ninth, and eleventh layers. Here, the layers are numbered in order from the side of the substrate. The layers of SiO₂ as a low refractive index material are arranged as the 45 second, fourth, sixth, eighth, and tenth layers. The layer of MgF₂ as a low refractive index material is arranged as the twelfth layer (the outermost layer).

As shown in FIGS. 18 and 19, in the wavelength range of 400 nm to 680 nm, the antireflection coating according to example 10 has a reflectance of 1.26% at the maximum and 0.93% on an average, which is lower than 1.5%, and in the wavelength range of 680 nm to 1350 nm, the antireflection coating according to example 10 has a reflectance of 0.97% at the maximum and 0.75% on an average, showing a 55 reflectance characteristic lower than 2.0%.

Example 13

In the antireflection coatings according to the abovedescribed examples, an additional layer (s) may be provided between the optical element and the first layer and/or on the outer side of the twelfth layer for the purpose of enhancing the adhesion to the surface of an optical element or enhancing water repellency, anti-fogging, and/or durability of the outermost layer of the optical element applied with the antireflection coating, as long as optical characteristics are not affected significantly.

As an example of such an arrangement, the antireflection coating according to example 13 has an SiO₂ overcoating applied on the outer side of the twelfth layer of the deposition structure having the same layers as example 10.

Specifically, as shown in FIG. 24, the antireflection coating according to example 13 has a deposition structure made up of twelve layers in which layers of Ta₂O₅ (having a refractive index nH of 2.22) as a high refractive index material and layers of SiO₂ (having a refractive index nL of 1.45) or MgF₂ (having a refractive index nL of 1.38) as a low refractive index material are deposited alternately on a substrate having a refractive index of 1.49 and additionally has a layer of SiO₂ as the thirteenth layer deposited on the outermost layer. The layers of Ta_2O_5 as a high refractive index material are arranged as the first, third, fifth, seventh, ninth, and eleventh layers. Here, the layers are numbered in

Example 11

As shown in FIG. 20, the antireflection coating according 60 to example 11 has a deposition structure made up of twelve layers in which layers of HfO₂ (having a refractive index nH of 1.99) as a high refractive index material and layers of SiO₂ (having a refractive index nL of 1.45) or MgF₂ (having a refractive index nL of 1.38) as a low refractive index 65 material are deposited alternately on a substrate having a refractive index of 1.57. The layers of HfO₂ as a high

15

order from the side of the substrate. The layers of SiO_2 as a low refractive index material are arranged as the second, fourth, sixth, eighth, tenth, and thirteenth layers. The layer of MgF₂ as a low refractive index material is arranged as the twelfth layer.

As shown in FIGS. **19** and **25**, in the wavelength range of 400 nm to 680 nm, the antireflection coating according to example 13 has a reflectance of 1.26% at the maximum and 0.93% on an average, which is lower than 1.5%, and in the wavelength range of 680 nm to 1350 nm, the antireflection 10 coating according to example 13 has a reflectance of 0.97% at the maximum and 0.75% on an average, showing a reflectance characteristic lower than 2.0%.

16

exposed to air and defining a light receiving surface, the outermost layer being a layer of MgF2, the reflectance of the antireflection coating relative to light impinging on the light receiving surface being not higher than 1.5% throughout the wavelength range of 400 nm to 680 nm and not higher than 2.0% throughout in the wavelength range of 680 nm to 1350 nm, wherein the coating is formed on a substrate and the high refractive index layers are arranged as first, third, fifth, seventh, ninth, and eleventh layers, the low refractive index layers are arranged as second, fourth, sixth, eighth, tenth, and twelfth layers, where the layers are numbered in order from the side of the substrate, and the optical layer thickness OT of each respective layer is defined as the product of its refractive index and its physical film thickness, the optical 15 thickness OT of each of the respective layers satisfying the following conditions: 1st layer: 0.11<OT<0.25, 2nd layer: 0.33<OT<0.72, 3rd layer: 0.33<OT<0.60, 4th layer: 0.23 < OT < 0.54, 5th layer: 0.63 < OT < 0.88, 6th layer: 0.08<OT<0.22, 7th layer: 1.23<OT<2.29, 8th layer: 0.06<OT<0.15, 9th layer: 0.59<OT<0.94, 10th layer: 0.34<OT<0.44, 11th layer: 0.23<OT<0.42, and 12th layer: 1.15<OT<1.27. 2. The antireflection coating according to claim 1, wherein the high refractive index material is TiO_2 , Nb_2O_5 , Ta₂O₅, HfO₂, or a mixture of these materials with La and/or Zr, and the low refractive index material is SiO_2 , MgF₂, or a mixture of SiO₂ and MgF₂. 3. The antireflection coating according to claim 1, wherein the refractive index of the substrate is in the range 30 from 1.48 to 1.8. **4**. An optical system comprising two or more substrates on which an antireflection coating according to claim 1 is formed.

INDUSTRIAL APPLICABILITY

As described in the foregoing, the antireflection coating according to the present invention is useful for use in a multiphoton absorption microscope that needs an antireflection coating for an objective lens in a wavelength range 20 ranging from the visible right range to the near infrared range.

REFERENCE SIGNS LIST

101: layer source

102: multi-layer filter

103: observation table

110: optical system

S: object to be observed

The invention claimed is:

1. An antireflection coating comprising a deposition structure made up of twelve layers in which layers of a high refractive index material having a refractive index of 1.95 to 2.32 and layers of a low refractive index material having a 35 refractive index of 1.35 to 1.46 are alternately stacked one on top of the other with an outermost one of the layers being

5. An optical instrument comprising an optical system according to claim 4.

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